

MOS FIELD EFFECT TRANSISTOR $\mu PA2802$

SWITCHING N-CHANNEL POWER MOSFET

RATINGS ($T_A = 25^{\circ}C$, All terminals are

DESCRIPTION

The μ PA2802 is N-channel MOSFET designed for DC/DC converter and power management applications of portable equipments.

FEATURES

- Low on-state resistance
- $R_{DS(on)1} = 5.8 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, \text{ ID} = 18 \text{ A})$
- $R_{DS(on)2} = 10 \text{ m}\Omega \text{ MAX.} (V_{GS} = 4.5 \text{ V}, \text{ ID} = 9 \text{ A})$

MAXIMUM

- Built-in gate protection diode
- Thin type surface mount package with heat spreader
- RoHS Compliant

ABSOLUTE

connected.)	·	·	
Drain to Source Voltage (Vgs = 0 V)	VDSS	20	V
Gate to Source Voltage (VDs = 0 V)	Vgss	±20	V
Drain Current (DC)	D(DC)	±18	А
Drain Current (pulse) ^{Note1}	D(pulse)	±72	А
Total Power Dissipation Note2	PT1	1.5	W
Total Power Dissipation (PW = 10 sec) Note2	Pt2	3.8	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note3	las	18	А
Single Avalanche Energy ^{Note3}	Eas	32.4	mJ
THERMAL RESISTANCE			

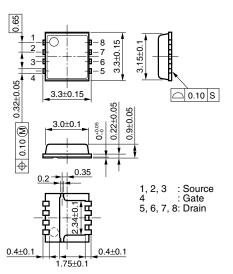
Channel to Ambient Thermal Resistance Note2	Rth(ch-A)	83.3	°C/W
Channel to Case (Drain) Thermal Resistance	Rth(ch-C)	2.4	°C/W

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

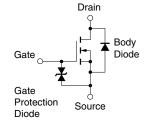
- 2. Mounted on FR-4 board of 25.4 mm x 25.4 mm x 0.8 mmt
- 3. Starting T_{ch} = 25°C, V_{DD} = 10 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V, L = 100 μ H
- **Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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EQUIVALENT CIRCUIT



CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 20 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	Igss	V _{GS} = ±12 V, V _{DS} = 0 V			±10	μA
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.0		2.5	v
Forward Transfer Admittance Note	yfs	V _{DS} = 10 V, I _D = 9 A	6			S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = 10 V, I _D = 18 A		4.6	5.8	mΩ
	RDS(on)2	V _{GS} = 4.5 V, I _D = 9 A		7.5	10	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V,		1800		pF
Output Capacitance	Coss	V _{GS} = 0 V,		380		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		190		pF
Turn-on Delay Time	td(on)	V _{DD} = 10 V, I _D = 9 A,		14		ns
Rise Time	tr	V _{GS} = 10 V,		48		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		49		ns
Fall Time	tr			11		ns
Total Gate Charge	QG	V _{DD} = 10 V,		16		nC
Gate to Source Charge	QGS	V _{GS} = 5 V,		6		nC
Gate to Drain Charge	Qgd	I _D = 18 A		6		nC
Body Diode Forward Voltage ^{Note}	VF(S-D)	IF = 18 A, VGS = 0 V		0.82	1.2	v
Reverse Recovery Time	trr	I⊧ = 18 A, V _{GS} = 0 V,		32		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs 26			nC	
Gate Resistance	Rg	f = 1 MHz		1.6		Ω

ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)

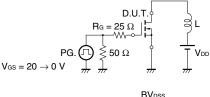
Note Pulsed

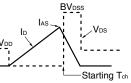
TEST CIRCUIT 1 AVALANCHE CAPABILITY

TEST CIRCUIT 2 SWITCHING TIME

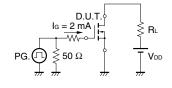
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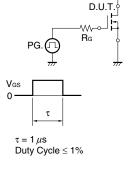
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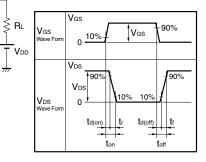




TEST CIRCUIT 3 GATE CHARGE



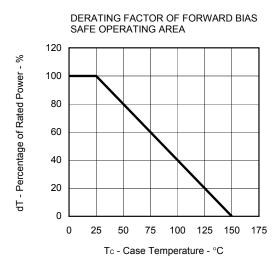




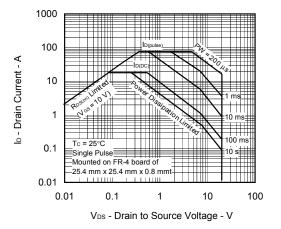
Data Sheet G19568EJ1V0DS

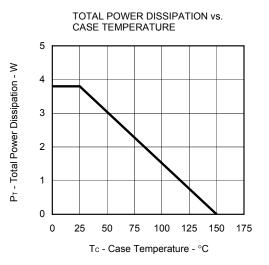
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TYPICAL CHARACTERISTICS (TA = 25°C)

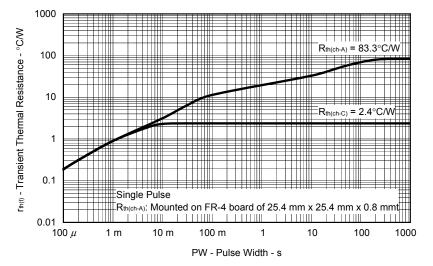




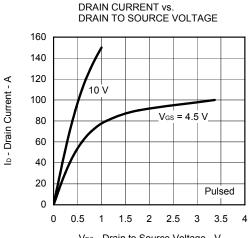




TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

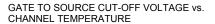


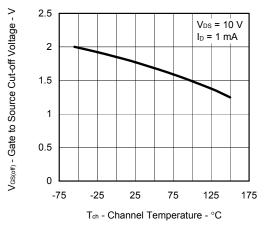
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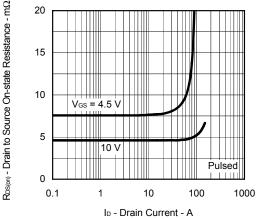
NEC

 V_{DS} - Drain to Source Voltage - V

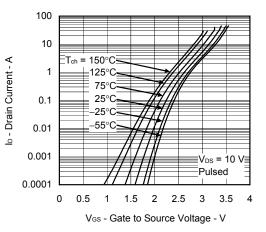




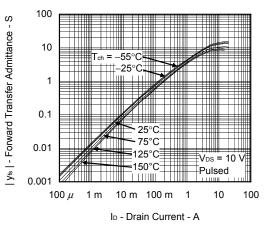




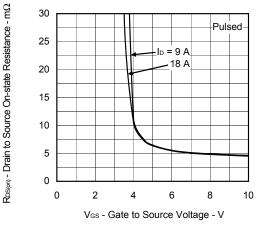




FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

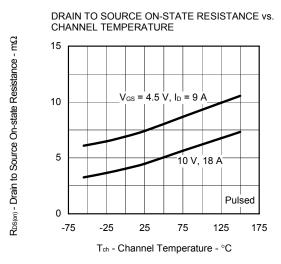


DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

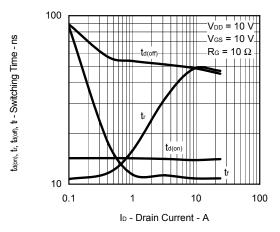


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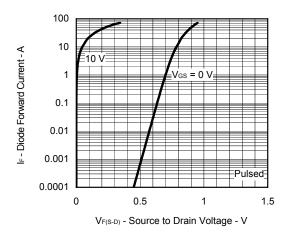
Data Sheet G19568EJ1V0DS

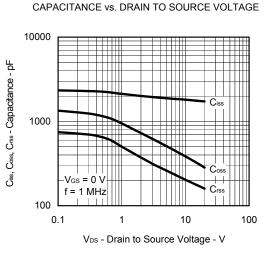




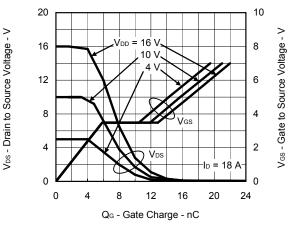


SOURCE TO DRAIN DIODE FORWARD VOLTAGE

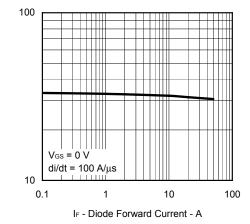




DYNAMIC INPUT/OUTPUT CHARACTERISTICS

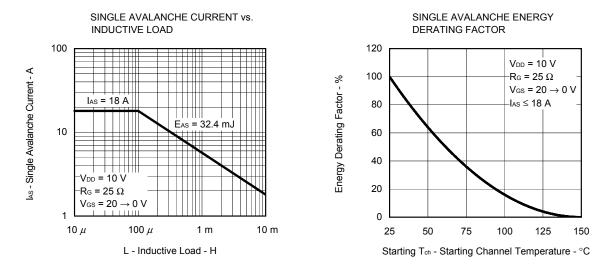






Data Sheet G19568EJ1V0DS

tr - Reverse Recovery Time - ns



ORDERING INFORMATION

NEC

PART NUMBER	LEAD PLATING	PACKING	PACKAGE	
μΡΑ2802Τ1L-Ε1-ΑΥ ^{Note}	_		8-pin HVSON (3333)	
μΡΑ2802Τ1L-Ε2-ΑΥ ^{Note}	Pure Sn	Tape 3000 p/reel	0.028 g TYP.	

Note Pb-free (This product does not contain Pb in the external electrode.)

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